

$I_{F(AV)} = 1.0 \text{ Amp}$
 $V_R = 30V$

Major Ratings and Characteristics

Characteristics	STPS1L30U	Units
$I_{F(AV)}$ Rectangular waveform	1.0	A
V_{RRM}	30	V
I_{FSM} @ $t_p = 5 \text{ ms}$ sine	360	A
V_F @ 1.0 Apk , $T_J = 125^\circ\text{C}$	0.30	V
T_J range	- 55 to 150	$^\circ\text{C}$

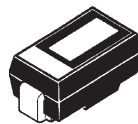
Description/ Features

The STPS1L30U surface-mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, free-wheeling diodes, battery charging, and reverse battery protection.

- Small foot print, surface mountable
- Very low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability

Case Styles

STPS1L30U



SMB



Voltage Ratings

Part number	STPS1L30U
V _R Max. DC Reverse Voltage (V)	30
V _{RWM} Max. Working Peak Reverse Voltage (V)	

Absolute Maximum Ratings

Parameters	Value	Units	Conditions
I _{F(AV)} Max. Average Forward Current	1.0	A	50% duty cycle @ T _L = 106 °C, rectangular wave form
I _{FSM} Max. Peak One Cycle Non-Repetitive Surge Current	360	A	5µs Sine or 3µs Rect. pulse
	75		10ms Sine or 6ms Rect. pulse
E _{AS} Non-Repetitive Avalanche Energy	3.0	mJ	T _J = 25 °C, I _{AS} = 1A, L = 6mH
I _{AR} Repetitive Avalanche Current	1.0	A	Current decaying linearly to zero in 1 µsec Frequency limited by T _J max. Va = 1.5 x Vr typical

Electrical Specifications

Parameters	Value	Units	Conditions
V _{FM} Max. Forward Voltage Drop (1)	0.420	V	@ 1A
	0.470	V	@ 2A
	0.300	V	@ 1A
	0.375	V	@ 2A
I _{RM} Max. Reverse Leakage Current (1)	0.2	mA	T _J = 25 °C
	5.0	mA	T _J = 100 °C
	15	mA	T _J = 125 °C
C _T Max. Junction Capacitance	200	pF	V _R = 5V _{DC} , (test signal range 100KHz to 1Mhz) 25°C
L _S Typical Series Inductance	2.0	nH	Measured lead to lead 5mm from package body
dv/dt Max. Voltage Rate of Change (Rated V _R)	10000	V/µs	

(1) Pulse Width < 300µs, Duty Cycle < 2%

Thermal-Mechanical Specifications

Parameters	Value	Units	Conditions
T _J Max. Junction Temperature Range (*)	-55 to 150	°C	
T _{stg} Max. Storage Temperature Range	-55 to 150	°C	
R _{thJL} Max. Thermal Resistance Junction to Lead (**)	25	°C/W	DC operation
R _{thJA} Max. Thermal Resistance Junction to Ambient	80	°C/W	DC operation
wt Approximate Weight	0.10(0.003)	g (oz.)	
Case Style	SMB		Similar to DO-214AA
Device Marking	IR13L		

(*) $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{th(j-a)}}$ thermal runaway condition for a diode on its own heatsink

(**) Mounted 1 inch square PCB

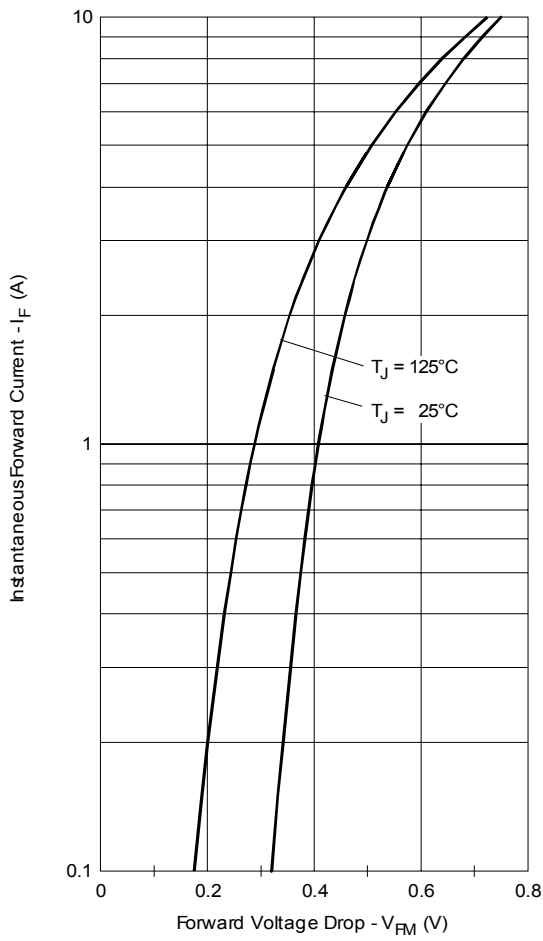


Fig. 1 - Maximum Forward Voltage Drop Characteristics

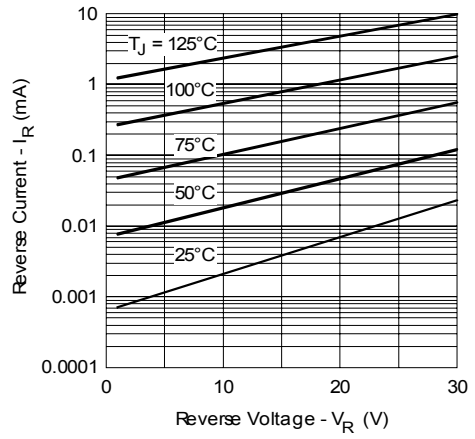


Fig. 2 - Typical Peak Reverse Current Vs. Reverse Voltage

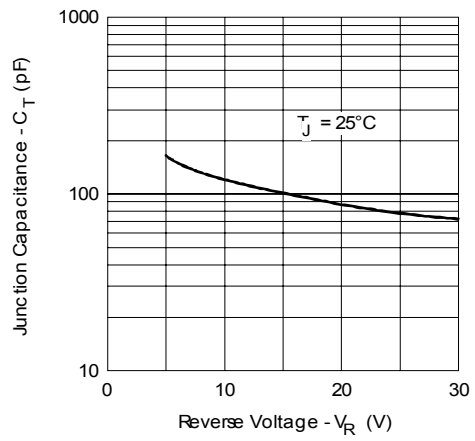


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage

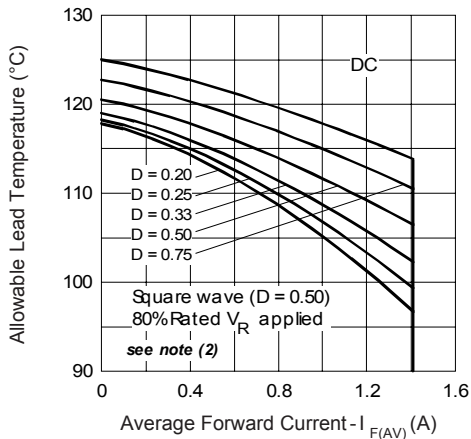


Fig. 4 - Maximum Average Forward Current Vs. Allowable Lead Temperature

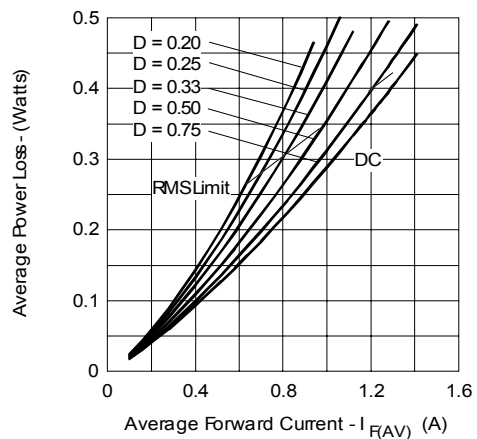


Fig. 5 - Maximum Average Forward Dissipation Vs. Average Forward Current

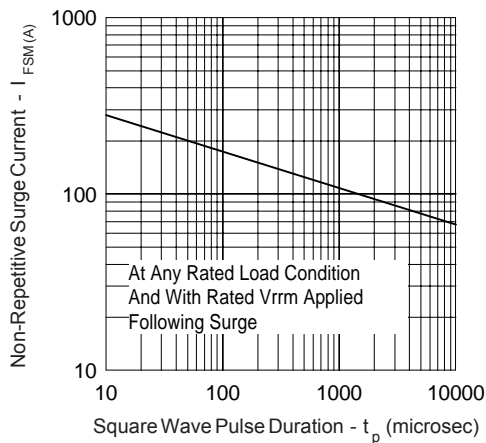


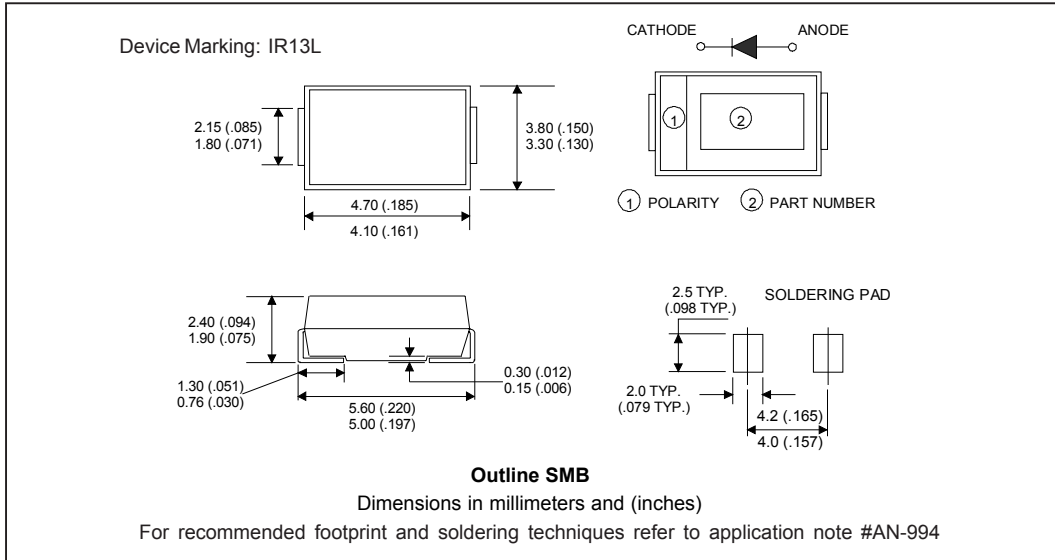
Fig. 6 - Maximum Peak Surge Forward Current Vs. Pulse Duration

(2) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

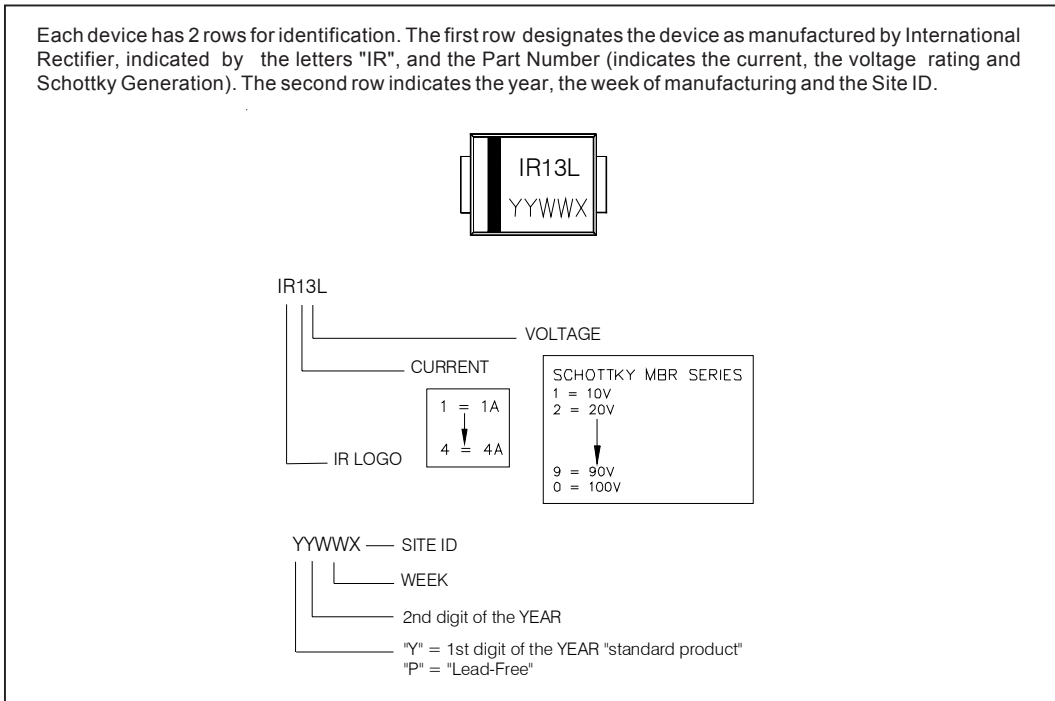
Pd = Forward Power Loss = $I_{F(AV)} \times V_{FM} @ (I_{F(AV)} / D)$ (see Fig. 6);

Pd_{REV} = Inverse Power Loss = $V_{R1} \times I_R (1 - D)$; $I_R @ V_{R1} = 80\%$ rated V_R

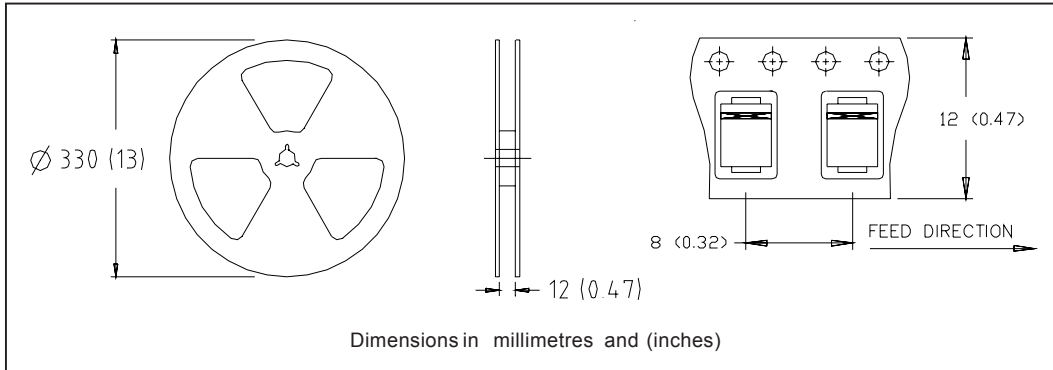
Outline Table



Marking & Identification



Tape & Reel Information



Ordering Information Table

Device Code					
STPS	1	L	30	U	-
①	②	③	④	⑤	⑥
1	-	Schottky STP Series			
2	-	Current Rating (1 = 1 A)			
3	-	L = Low Forward Voltage			
4	-	Voltage Rating (30 = 30V)			
5	-	U = SMB			
6	-	• none = Standard Production			
		• PbF = Lead-Free			
Tape & Reel only (3000 pieces)					

Data and specifications subject to change without notice.
This product has been designed and qualified for Industrial Level.
Qualification Standards can be found on IR's Web site.